





SN74HC10, SN54HC10

JAJSPQ5E - DECEMBER 1982 - REVISED APRIL 2021

# SNx4HC10 トリプル 3 入力 NAND ゲート

## 1 特長

- バッファ付き入力
- 広い動作電圧範囲:2V~6V
- 広い動作温度範囲: -40°C~+85°C
- 最大 10 個の LSTTL 負荷ファンアウトに対応
- LSTTL ロジック IC に比べて消費電力を大幅削減

## 2 アプリケーション

- アラーム/タンパ検出回路
- S-R ラッチ

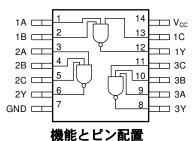
## 3 概要

このデバイスには、3 つの独立した 3 入力 NAND ゲート が内蔵されています。各ゲートはブール関数 Y =  $\overline{A \bullet B \bullet C}$  を正論理で実行します。

### 製品情報(1)

部品番号	パッケージ	本体サイズ (公称)
SN74HC10D	SOIC (14)	8.70mm × 3.90mm
SN74HC10N	PDIP (14)	19.30mm × 6.40mm
SN74HC10NS	SO (14)	10.20mm × 5.30mm
SN74HC10PW	TSSOP (14)	5.00mm × 4.40mm
SN54HC10J	CDIP (14)	21.30mm × 7.60mm
SN54HC10FK	LCCC (20)	8.90mm × 8.90mm

(1) 利用可能なパッケージについては、このデータシートの末尾にあ る注文情報を参照してください。





## **Table of Contents**

1 特長	1	8.2 Functional Block Diagram	
2 アプリケーション		8.3 Feature Description	
-		8.4 Device Functional Modes	10
4 Revision History		9 Application and Implementation	<mark>11</mark>
5 Pin Configuration and Functions		9.1 Application Information	11
Pin Functions		9.2 Typical Application	
6 Specifications		10 Power Supply Recommendations	13
6.1 Absolute Maximum Ratings		11 Layout	13
6.2 Recommended Operating Conditions		11.1 Layout Guidelines	13
6.3 Thermal Information		11.2 Layout Example	13
6.4 Electrical Characteristics - 74		12 Device and Documentation Support	14
6.5 Electrical Characteristics - 54		12.1 Documentation Support	14
6.6 Switching Characteristics - 74		12.2 Related Links	14
6.7 Switching Characteristics - 54		12.3 サポート・リソース	14
6.8 Operating Characteristics		12.4 Trademarks	14
6.9 Typical Characteristics		12.5 静電気放電に関する注意事項	14
7 Parameter Measurement Information		12.6 用語集	
8 Detailed Description		13 Mechanical, Packaging, and Orderable	
8.1 Overview		Information	14

# **4 Revision History**

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

С	hanges from Revision D (August 2003) to Revision E (April 2021)	Page
•	文書全体にわたって表、図、相互参照の採番方法を更新	1
•	新しいデータシート標準に更新	1
	R <sub>0JA</sub> increased for the D, DB, and PW packages and decreased for the N and NS packages	4



# **5 Pin Configuration and Functions**

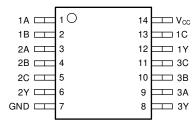


図 5-1. D, N, NS, PW, or J Package 14-Pin SOIC, PDIP, SO, TSSOP, or CDIP Top View

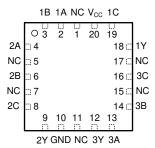


図 5-2. FK Package 20-Pin LCCC Top View

## **Pin Functions**

	PIN			
NAME	D, N, NS, PW, or J	FK	I/O	DESCRIPTION
1A	1	2	Input	Channel 1, Input A
1B	2	3	Input	Channel 1, Input B
2A	3	4	Input	Channel 2, Input A
2B	4	6	Input	Channel 2, Input B
2C	5	8	Input	Channel 2, Input C
2Y	6	9	Output	Channel 2, Output Y
GND	7	10	_	Ground
3Y	8	12	Output	Channel 3, Output Y
ЗА	9	13	Input	Channel 3, Input A
3B	10	14	Input	Channel 3, Input B
3C	11	16	Input	Channel 3, Input C
1Y	12	18	Output	Channel 1, Output Y
1C	13	19	Input	Channel 1, Input C
V <sub>CC</sub>	14	20	_	Positive Supply
NC		1, 5, 7, 11, 15, 17	_	Not internally connected



## **6 Specifications**

## **6.1 Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		-0.5	7	V
I <sub>IK</sub>	Input clamp current <sup>(2)</sup>	$V_{l} < 0$ or $V_{l} > V_{CC}$		±20	mA
I <sub>OK</sub>	Output clamp current <sup>(2)</sup>	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	V <sub>O</sub> = 0 to V <sub>CC</sub>		±25	mA
	Continuous current through V <sub>CC</sub> or GND			±50	mA
TJ	Junction temperature <sup>(3)</sup>			150	°C
T <sub>stg</sub>	Storage temperature		-65	150	°C

- (1) Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Condition. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability
- (2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) Guaranteed by design.

## **6.2 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V <sub>CC</sub>	Supply voltage	-	2	5	6	V
		V <sub>CC</sub> = 2 V	1.5			
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 4.5 V	3.15			V
		V <sub>CC</sub> = 6 V	4.2			
		V <sub>CC</sub> = 2 V			0.5	
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 4.5 V			1.35	V
		V <sub>CC</sub> = 6 V			1.8	
VI	Input voltage	·	0		V <sub>CC</sub>	V
Vo	Output voltage		0		V <sub>CC</sub>	V
		V <sub>CC</sub> = 2 V			1000	
Δt/Δν	Input transition rise and fall rate	V <sub>CC</sub> = 4.5 V			500	ns
		V <sub>CC</sub> = 6 V			400	
т	Operating free air temperature	SN54HC10	-55		125	°C
T <sub>A</sub>	Operating free-air temperature	SN74HC10	-40		85	C

#### **6.3 Thermal Information**

	THERMAL METRIC(1)	D (SOIC)	DB (SSOP)	N (PDIP)	NS (SOP)	PW (TSSOP)	UNIT
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	133.6		67.5	122.6	151.7	°C/W
R <sub>θ</sub> JC(top)	Junction-to-case (top) thermal resistance	89.0		55.6	81.8	79.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	89.5		47.2	83.8	94.7	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	45.5		35.6	45.4	25.2	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	89.1		47.0	83.4	94.1	°C/W

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	THERMAL METRIC <sup>(1)</sup>	D (SOIC)	D (SOIC) DB (SSOP) N (PDIP) NS (SOP)				UNIT
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
R <sub>θ</sub> JC(bot)	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	N/A	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

#### 6.4 Electrical Characteristics - 74

over operating free-air temperature range; typical values measured at T<sub>A</sub> = 25°C (unless otherwise noted).

					О	perating	free-air	temperat	ure (T <sub>A</sub> )		
P	PARAMETER		CONDITIONS	V <sub>cc</sub>		25°C		-40°	C to 85°0	3	UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
				2 V	1.9	1.998		1.9			
		., .,	I <sub>OH</sub> = -20 μA	4.5 V	4.4	4.499		4.4			
V <sub>OH</sub>	High-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>II</sub>		6 V	5.9	5.999		5.9			V
			I <sub>OH</sub> = -4 mA	4.5 V	3.98	4.3		3.84			
		I <sub>OH</sub> = -5.2 mA	6 V	5.48	5.8		5.34				
		put V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 20 μA	2 V		0.002	0.1			0.1	
			ΙΟΣ - 20 μΛ	4.5 V		0.001	0.1			0.1	
V <sub>OL</sub>	voltage		I <sub>OL</sub> = 20 μA	6 V		0.001	0.1			0.1	V
			I <sub>OL</sub> = 4 mA	4.5 V		0.17	0.26			0.33	
			I <sub>OL</sub> = 5.2 mA	6 V		0.15	0.26			0.33	
I	Input leakage current	V <sub>I</sub> = V <sub>CC</sub> o	r 0	6 V			±0.1			±1	μΑ
I <sub>CC</sub>	Supply current	V <sub>I</sub> = V <sub>CC</sub> or 0	V <sub>I</sub> = V <sub>CC</sub> or 0	6 V			2			20	μΑ
C <sub>i</sub>	Input capacitance			2 V to 6 V		3	10			10	pF

#### 6.5 Electrical Characteristics - 54

over operating free-air temperature range; typical values measured at TA = 25°C (unless otherwise noted).

							Opera	ting free	-air tem	peratur	e (T <sub>A</sub> )				
F	PARAMETER	R TEST CONDITIONS		V <sub>CC</sub>		25°C		–40°	°C to 85°	,C	–55°(	-55°C to 125°C			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX		
				2 V	1.9	1.998		1.9			1.9				
			I <sub>OH</sub> = -20 μΑ	4.5 V	4.4	4.499		4.4			4.4				
.,	High-level	$V_I = V_{IH}$ or	-	6 V	5.9	5.999		5.9			5.9			.,	
V <sub>OH</sub>	output voltage	age V <sub>IL</sub>	$V_{IL}$	I <sub>OH</sub> = -4 mA	4.5 V	3.98	4.3								V
			I <sub>OH</sub> = -5.2 mA	6 V	5.48	5.8									
				2 V		0.002	0.1			0.1			0.1		
			I <sub>OL</sub> = 20 μΑ	4.5 V		0.001	0.1			0.1			0.1		
V <sub>OL</sub>	Low-level output		'	6 V		0.001	0.1			0.1			0.1	v	
	voltage	V <sub>IL</sub>	I <sub>OL</sub> = 4 mA	4.5 V		0.17	0.26			0.33			0.4		
			I <sub>OL</sub> = 5.2 mA	6 V		0.15	0.26			0.33			0.4		
I <sub>I</sub>	Input leakage current	V <sub>I</sub> = V <sub>CC</sub> or	0	6 V			±0.1			±1			±1	μA	

over operating free-air temperature range; typical values measured at TA = 25°C (unless otherwise noted).

	PARAMETER TEST CONDITIONS		-		Operating free-air temperature (T <sub>A</sub> )																	
ı			TEST CONDITIONS		TEST CONDITIONS		TEST CONDITIONS		TEST CONDITIONS		TEST CONDITIONS		T CONDITIONS V		TEST CONDITIONS V <sub>CC</sub>		25°C			-40°C to 85°C		-55°C to 125°C
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX									
I <sub>CC</sub>	Supply current	V <sub>I</sub> = V <sub>CC</sub> or 0	I <sub>O</sub> = 0	6 V			2			20			40	μА								
Ci	Input capacitance			2 V to 6 V		3	10			10			10	pF								

## 6.6 Switching Characteristics - 74

over operating free-air temperature range (unless otherwise noted)

					Op	erating	free-air	temperat	ture (T <sub>A</sub> )		
	PARAMETER		то	V <sub>cc</sub>	25°C			–40°	°C to 85°	C	UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
				2 V		35	95		,	120	
t <sub>pd</sub>	Propagation delay	A, B, or C	Υ	4.5 V		10	19			24	ns
				6 V		9	16			20	
				2 V		23	75			95	
t <sub>t</sub>	Transition-time		Y	4.5 V		6	15			19	ns
				6 V		5	13			16	

## 6.7 Switching Characteristics - 54

over operating free-air temperature range; typical values measured at TA = 25°C (unless otherwise noted).

PARAMETER					Operating free-air temperature (T <sub>A</sub> )									
		FROM	то	V <sub>cc</sub>	25°C			-40°	°C to 8	5°C	-55°C to 125°C			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
	Propagation delay	A , B, or C		2 V		35	95			120			145	
t <sub>pd</sub>			Y	4.5 V		10	19			24			29	ns
				6 V		9	16			20			25	
			Y	2 V		23	75			95			110	
t <sub>t</sub>	Transition-time			4.5 V		6	15			19			22	ns
				6 V		5	13			16			19	

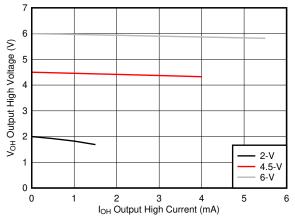
## 6.8 Operating Characteristics

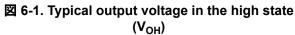
over operating free-air temperature range; typical values measured at T<sub>A</sub> = 25°C (unless otherwise noted).

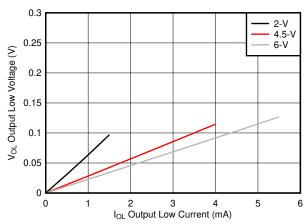
	0 1	0 / 11				
	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP MAX	UNIT
Cnd	Power dissipation capacitance per gate	No load	2 V to 6 V		25	pF

## **6.9 Typical Characteristics**

 $T_A = 25^{\circ}C$ 





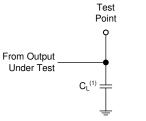


 $\boxtimes$  6-2. Typical output voltage in the low state (V $_{\rm OL})$ 



## 7 Parameter Measurement Information

- Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z<sub>O</sub> = 50 Ω, t<sub>t</sub> < 6 ns.</li>
- The outputs are measured one at a time, with one input transition per measurement.



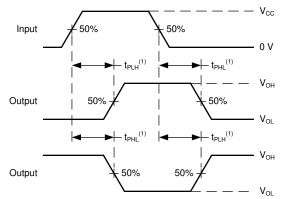
Input 00%

A. C<sub>L</sub>= 50 pF and includes probe and jig capacitance.

図 7-1. Load Circuit

A. t<sub>t</sub> is the greater of t<sub>r</sub> and t<sub>f</sub>.

## 図 7-2. Voltage Waveforms Transition Times



A. The maximum between  $t_{PLH}$  and  $t_{PHL}$  is used for  $t_{pd}$ .

図 7-3. Voltage Waveforms Propagation Delays

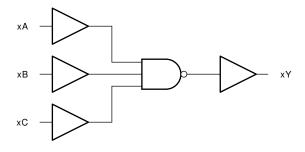


## 8 Detailed Description

#### 8.1 Overview

This device contains three independent 3-input NAND gates. Each gate performs the Boolean function  $Y = \overline{A \bullet B \bullet C}$  in positive logic.

## 8.2 Functional Block Diagram



## 8.3 Feature Description

## 8.3.1 Balanced CMOS Push-Pull Outputs

A balanced output allows the device to sink and source similar currents. The drive capability of this device may create fast edges into light loads so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. It is important for the output power of the device to be limited to avoid damage due to overcurrent. The electrical and thermal limits defined in the *Absolute Maximum Ratings* must be followed at all times.

The SN74HC10 can drive a load with a total capacitance less than or equal to the maximum load listed in the Switching Characteristics - 74 connected to a high-impedance CMOS input while still meeting all of the datasheet specifications. Larger capacitive loads can be applied, however it is not recommended to exceed the provided load value. If larger capacitive loads are required, it is recommended to add a series resistor between the output and the capacitor to limit output current to the values given in the Absolute Maximum Ratings.

#### 8.3.2 Standard CMOS Inputs

Standard CMOS inputs are high impedance and are typically modeled as a resistor from the input to ground in parallel with the input capacitance given in the *Electrical Characteristics - 74*. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings*, and the maximum input leakage current, given in the *Electrical Characteristics - 74*, using ohm's law  $(R = V \div I)$ .

Signals applied to the inputs need to have fast edge rates, as defined by the input transition time in the *Recommended Operating Conditions* to avoid excessive current consumption and oscillations. If a slow or noisy input signal is required, a device with a Schmitt-trigger input should be used to condition the input signal prior to the standard CMOS input.

#### 8.3.3 Clamp Diode Structure

The inputs and outputs to this device have both positive and negative clamping diodes as depicted in 🗵 8-1.

#### 注意

Voltages beyond the values specified in the  $\cancel{\text{tDys}}$  6.1 table can cause damage to the device. The recommended input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

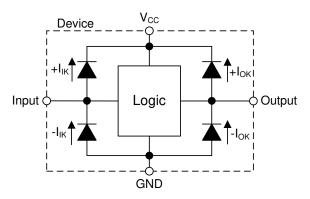


図 8-1. Electrical Placement of Clamping Diodes for Each Input and Output

#### **8.4 Device Functional Modes**

表 8-1. Function Table

	INPUTS	OUTPUT				
Α	В	Y				
Н	Н	Н	L			
L	Х	Х	Н			
Х	L	Х	Н			
Х	Х	L	Н			

## 9 Application and Implementation

注

以下のアプリケーション情報は、TIの製品仕様に含まれるものではなく、TIではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくことになります。また、お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

### 9.1 Application Information

In this application, two 3-input NAND gates are used to create an active-low SR latch as shown in  $\boxed{2}$  9-1. The additional gate can be used for another application, or the inputs can be grounded and the channel left unused.

This device is used to drive the tamper indicator LED and provide one bit of data to the system controller. When the tamper switch outputs LOW, the output Q becomes HIGH. This output remains HIGH until the system controller addresses the event and sends a LOW signal to the R input which returns the Q output back to LOW.

## 9.2 Typical Application

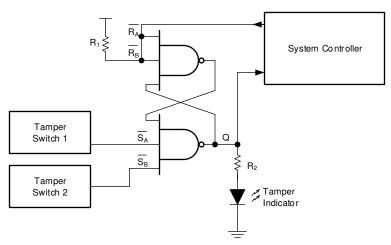


図 9-1. Typical application schematic

#### 9.2.1 Design Requirements

#### 9.2.1.1 Power Considerations

Ensure the desired supply voltage is within the range specified in the *Recommended Operating Conditions*. The supply voltage sets the device's electrical characteristics as described in the *Electrical Characteristics - 74*.

The supply must be capable of sourcing current equal to the total current to be sourced by all outputs of the SN74HC10 plus the maximum supply current,  $I_{CC}$ , listed in the *Electrical Characteristics - 74*. The logic device can only source or sink as much current as it is provided at the supply and ground pins, respectively. Be sure not to exceed the maximum total current through GND or  $V_{CC}$  listed in the *Absolute Maximum Ratings*.

Total power consumption can be calculated using the information provided in CMOS Power Consumption and  $C_{pd}$  Calculation.

Thermal increase can be calculated using the information provided in Thermal Characteristics of Standard Linear and Logic (SLL) Packages and Devices.

#### 注意

The maximum junction temperature,  $T_J(max)$  listed in the *Absolute Maximum Ratings*, is an *additional limitation* to prevent damage to the device. Do not violate any values listed in the *Absolute Maximum Ratings*. These limits are provided to prevent damage to the device.

#### 9.2.1.2 Input Considerations

Unused inputs must be terminated to either  $V_{CC}$  or ground. These can be directly terminated if the input is completely unused, or they can be connected with a pull-up or pull-down resistor if the input is to be used sometimes, but not always. A pull-up resistor is used for a default state of HIGH, and a pull-down resistor is used for a default state of LOW. The resistor size is limited by drive current of the controller, leakage current into the SN74HC10, as specified in the *Electrical Characteristics - 74*, and the desired input transition rate. A 10-k $\Omega$  resistor value is often used due to these factors.

The SN74HC10 has standard CMOS inputs, so input signal edge rates cannot be slow. Slow input edge rates can cause oscillations and damaging shoot-through current. The recommended rates are defined in the *Recommended Operating Conditions*.

Refer to セクション 8.3 for additional information regarding the inputs for this device.

#### 9.2.1.3 Output Considerations

The positive supply voltage is used to produce the output HIGH voltage. Drawing current from the output will decrease the output voltage as specified by the  $V_{OH}$  specification in the *Electrical Characteristics - 74*. Similarly, the ground voltage is used to produce the output LOW voltage. Sinking current into the output will increase the output voltage as specified by the  $V_{OI}$  specification in the *Electrical Characteristics - 74*.

Unused outputs can be left floating. Do not connect outputs directly to V<sub>CC</sub> or ground.

Refer to セクション 8.3 for additional information regarding the outputs for this device.

#### 9.2.2 Detailed Design Procedure

- 1. Add a decoupling capacitor from  $V_{CC}$  to GND. The capacitor needs to be placed physically close to the device and electrically close to both the  $V_{CC}$  and GND pins. An example layout is shown in  $\frac{1}{2}$
- 2. Ensure the capacitive load at the output is ≤ 70 pF. This is not a hard limit, however it will ensure optimal performance. This can be accomplished by providing short, appropriately sized traces from the SN74HC10 to the receiving device.
- Ensure the resistive load at the output is larger than (V<sub>CC</sub> / I<sub>O</sub>(max)) Ω. This will ensure that the maximum output current from the *Absolute Maximum Ratings* is not violated. Most CMOS inputs have a resistive load measured in megaohms; much larger than the minimum calculated above.
- 4. Thermal issues are rarely a concern for logic gates, however the power consumption and thermal increase can be calculated using the steps provided in the application report, CMOS Power Consumption and Cpd Calculation

#### 9.2.3 Application Curves

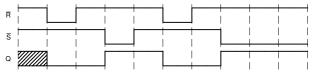


図 9-2. Typical application timing diagram



## 10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the  $\forall \forall \forall \exists \forall b \in \mathcal{C}$  for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- $\mu$ F and 1- $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results, as shown in  $\boxed{\mathbb{Z}}$  11-1.

## 11 Layout

### 11.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.

#### 11.2 Layout Example

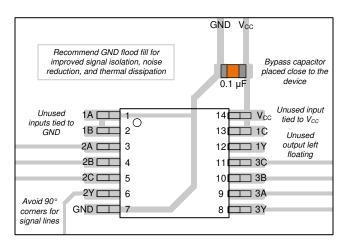


図 11-1. Example layout for the SN74HC10



## 12 Device and Documentation Support

## 12.1 Documentation Support

#### 12.1.1 Related Documentation

For related documentation see the following:

- HCMOS Design Considerations
- CMOS Power Consumption and CPD Calculation
- · Designing with Logic

#### 12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

### 12.3 サポート・リソース

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ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

#### 12.6 用語集

TI 用語集 この用語集には、用語や略語の一覧および定義が記載されています。

#### 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



www.ti.com 2-Dec-2023

## **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-8403801VCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8403801VC A SNV54HC10J	Samples
84038012A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	84038012A SNJ54HC 10FK	Samples
8403801CA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8403801CA SNJ54HC10J	Samples
8403801DA	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8403801DA SNJ54HC10W	Samples
JM38510/65002B2A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 65002B2A	Samples
JM38510/65002BCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 65002BCA	Samples
M38510/65002B2A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 65002B2A	Samples
M38510/65002BCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510/ 65002BCA	Samples
SN54HC10J	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	SN54HC10J	Samples
SN74HC10DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	HC10	Samples
SN74HC10N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HC10N	Samples
SN74HC10NE4	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HC10N	Samples
SN74HC10NSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC10	Samples
SN74HC10PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	HC10	Samples
SNJ54HC10FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	84038012A SNJ54HC 10FK	Samples
SNJ54HC10J	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8403801CA SNJ54HC10J	Samples

## PACKAGE OPTION ADDENDUM

www.ti.com 2-Dec-2023

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SNJ54HC10W	ACTIVE	CFP	W	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8403801DA SNJ54HC10W	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF SN54HC10, SN54HC10-SP, SN74HC10:



## **PACKAGE OPTION ADDENDUM**

www.ti.com 2-Dec-2023

• Catalog : SN74HC10, SN54HC10

• Automotive : SN74HC10-Q1, SN74HC10-Q1

• Enhanced Product : SN74HC10-EP, SN74HC10-EP

Military: SN54HC10

• Space : SN54HC10-SP

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

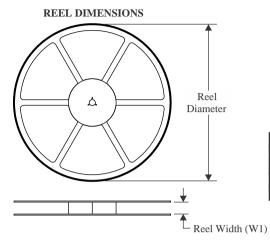
• Military - QML certified for Military and Defense Applications

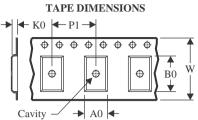
• Space - Radiation tolerant, ceramic packaging and qualified for use in Space-based application

**PACKAGE MATERIALS INFORMATION** 

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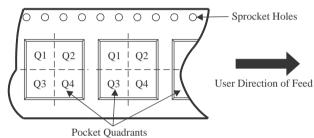
## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

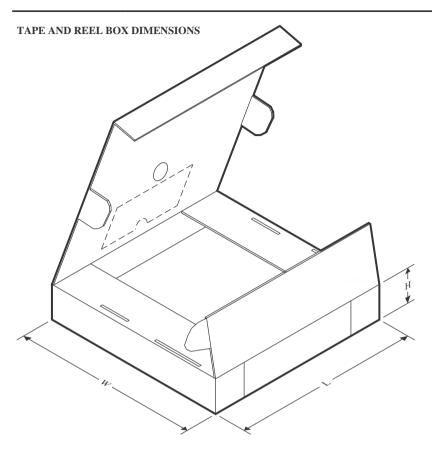


#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC10DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC10NSR	so	NS	14	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
SN74HC10PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC10PWR	TSSOP	PW	14	2000	330.0	12.4	6.85	5.45	1.6	8.0	12.0	Q1



www.ti.com 17-Jan-2024



#### \*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HC10DR	SOIC	D	14	2500	367.0	367.0	38.0
SN74HC10NSR	SO	NS	14	2000	356.0	356.0	35.0
SN74HC10PWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74HC10PWR	TSSOP	PW	14	2000	366.0	364.0	50.0

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 17-Jan-2024

## **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
84038012A	FK	LCCC	20	55	506.98	12.06	2030	NA
8403801DA	W	CFP	14	25	506.98	26.16	6220	NA
JM38510/65002B2A	FK	LCCC	20	55	506.98	12.06	2030	NA
M38510/65002B2A	FK	LCCC	20	55	506.98	12.06	2030	NA
SN74HC10N	N	PDIP	14	25	506	13.97	11230	4.32
SN74HC10N	N	PDIP	14	25	506	13.97	11230	4.32
SN74HC10NE4	N	PDIP	14	25	506	13.97	11230	4.32
SN74HC10NE4	N	PDIP	14	25	506	13.97	11230	4.32
SNJ54HC10FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54HC10W	W	CFP	14	25	506.98	26.16	6220	NA

## **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE

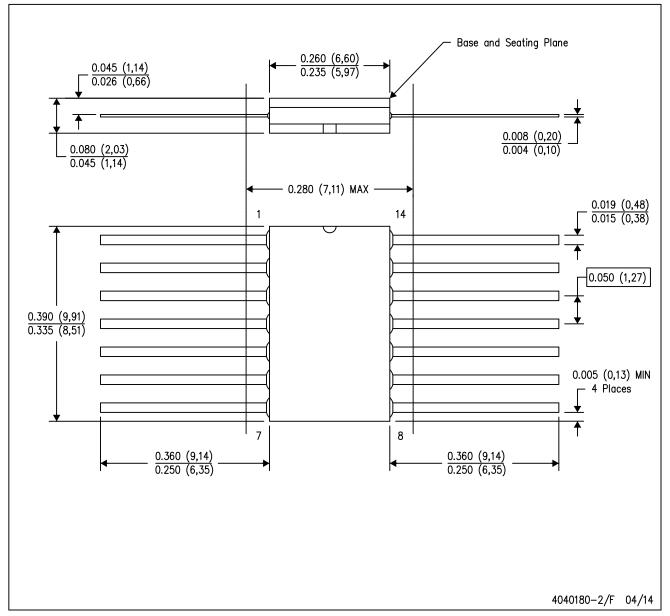


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



# W (R-GDFP-F14)

# CERAMIC DUAL FLATPACK



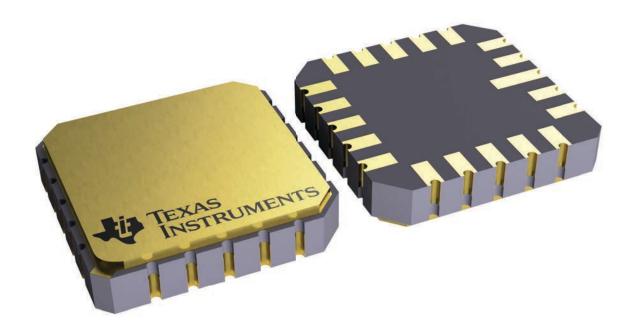
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14



8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



**INSTRUMENTS** www.ti.com

CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
   Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
   Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



# D (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



PW (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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